chanhvinh.com

ISP817X,ISP827X,ISP847X3,2,1
ISP817,ISP827,ISP847-3,-2,-1

ISOCOM COMPONENTS

LOW INPUT CURRENT PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS

ROHS COMPLIANT

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form : -
  - STD
  - G form
  - SMD approved to CECC 00802
- Certified to EN60950 by Nemko - Certificate No. P01102465

DESCRIPTION

The ISP817-3,-2,-1, ISP827-3,-2,-1, ISP847-3,-2,-1 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

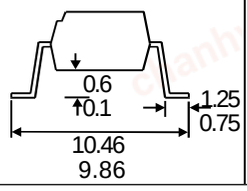
FEATURES

- Options :-
  10mm lead spread - add G after part no.
  Surface mount - add SM after part no.
  Tape&reel - add SMT&R after part no.
- Low input current 0.5mA I_F
- High Current Transfer Ratio (50% min)
- High Isolation Voltage (5.3kV$_{RMS}$,7.5kV$_{PK}$)
- High BV_{CEO} (70V min)
- All electrical parameters 100% tested
- Custom electrical selections available

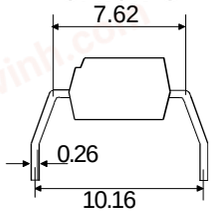
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

OPTION SM
SURFACE MOUNT

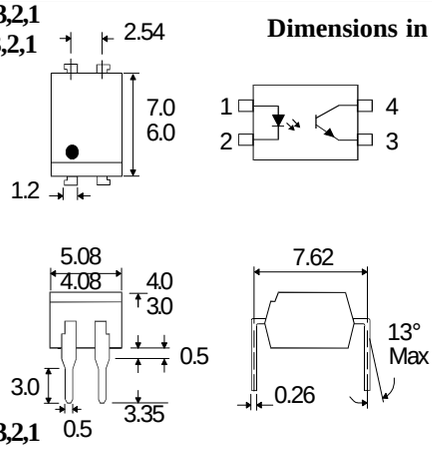


OPTION G

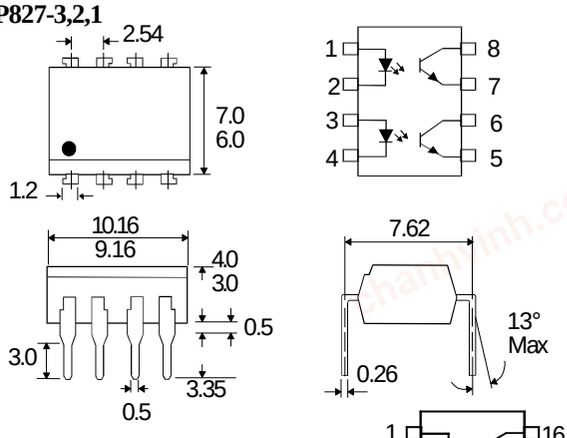


ISP817X3,2,1
ISP817-3,2,1

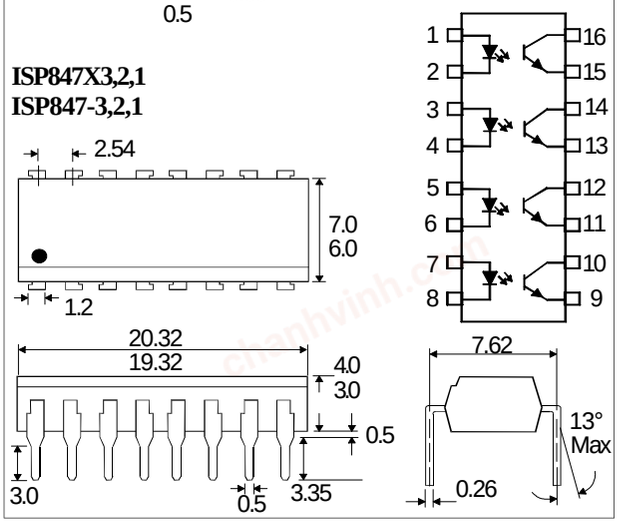
Dimensions in mm



ISP827X3,2,1
ISP827-3,2,1



ISP847X3,2,1
ISP847-3,2,1



ISOCOM COMPONENTS LTD
Unit 25B, Park View Road West,
Park View Industrial Estate, Brenda Road
Hartlepool, Cleveland, TS25 1YD
Tel: (01429) 863609 Fax :(01429) 863581

chanhvinh.com

ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 125°C
Operating Temperature	-30°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	70V
Emitter-collector Voltage BV_{ECO}	6V
Collector Current	50mA
Power Dissipation	150mW

POWER DISSIPATION

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

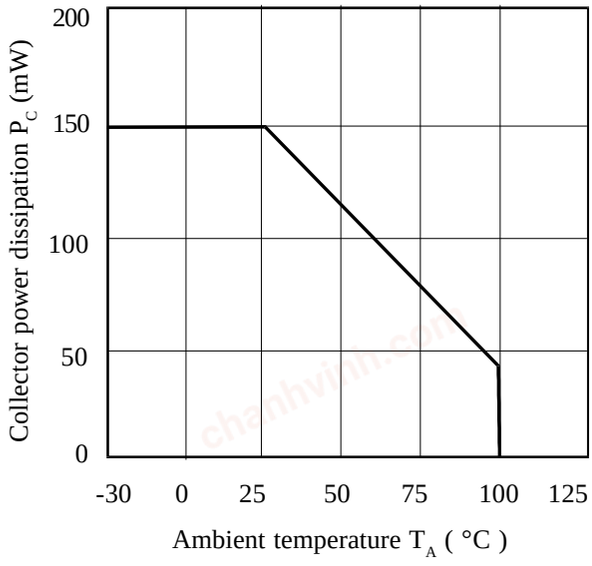
ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.4	V	I_F = 20mA
	Reverse Current (I_R)			10	µA	V_R = 4V
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	70			V	I_C = 1mA
	Emitter-collector Breakdown (BV_{ECO})	6			V	I_E = 10µA
	Collector-emitter Dark Current (I_{CEO})			100	nA	V_{CE} = 20V
Coupled	Current Transfer Ratio (CTR) (Note 2)					
	ISP817-3, ISP827-3, ISP847-3	70			%	0.5mA I_F, 0.4V V_{CE}
		100			%	1.0mA I_F, 0.4V V_{CE}
	ISP817-2, ISP827-2, ISP847-2	50			%	0.5mA I_F, 0.4V V_{CE}
	ISP817-1, ISP827-1, ISP847-1	50			%	1.0mA I_F, 0.4V V_{CE}
	Collector-emitter Saturation Voltage -3			0.4	V	0.5mA I_F, 0.35mA I_C
	-2			0.4	V	0.5mA I_F, 0.25mA I_C
	-1			0.4	V	1.0mA I_F, 0.5mA I_C
	Input to Output Isolation Voltage V_{ISO}	5300			V_{RMS}	See note 1
		7500			V_{PK}	See note 1
	Input-output Isolation Resistance R_{ISO}	$5x10^{10}$			Ω	V_{IO} = 500V (note 1)
	Output Rise Time tr		4	18	µs	V_{CE} = 2V ,
	Output Fall Time tf		3	18	µs	I_C = 2mA, R_L = 100Ω

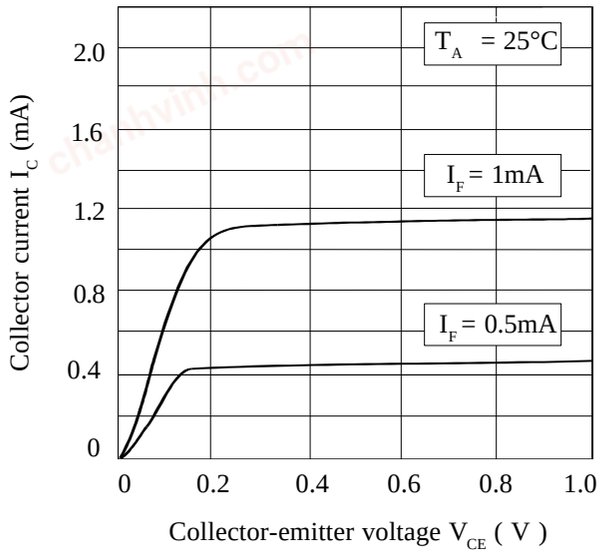
Note 1 Measured with input leads shorted together and output leads shorted together.
Note 2 Special Selections are available on request. Please consult the factory.

chanhvinh.com

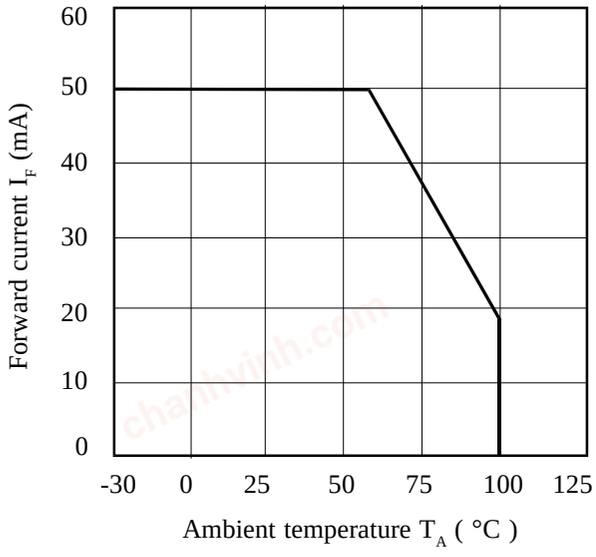
Collector Power Dissipation vs. Ambient Temperature



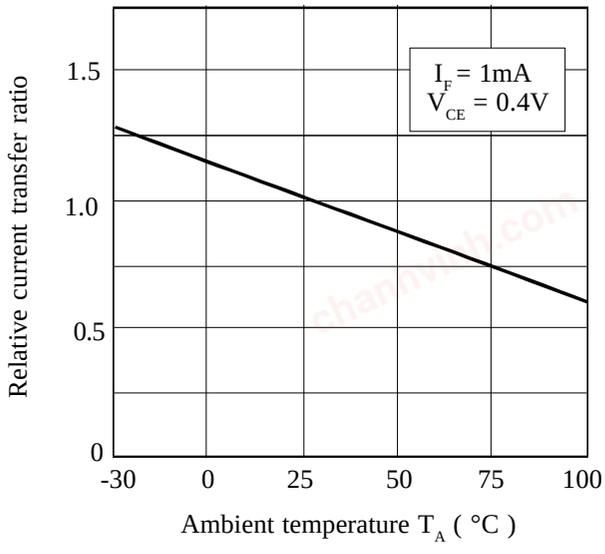
Collector Current vs. Low Collector-emitter Voltage



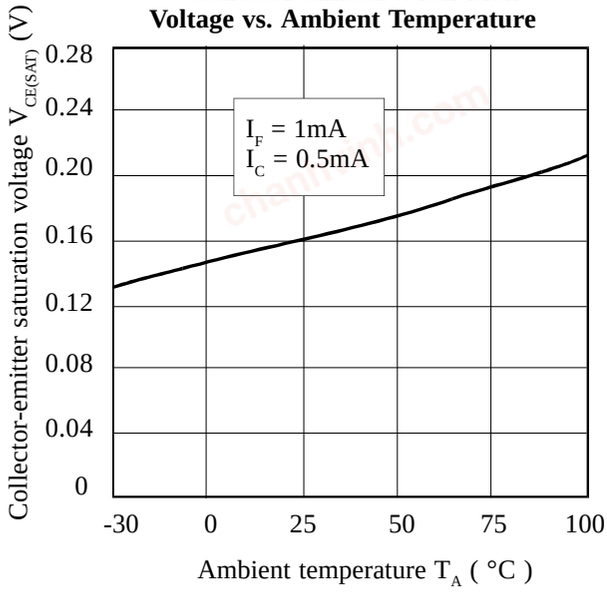
Forward Current vs. Ambient Temperature



Relative Current Transfer Ratio vs. Ambient Temperature



Collector-emitter Saturation Voltage vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current

